

1.25Gbps Burst-Mode Limiting Amplifier with Ultra-Fast Signal Assert Timing

General Description

The SY88149HAL is a high-sensitivity, burst-mode capable, limiting-post amplifier designed for FTTH PON optical line terminal (OLT) receiver applications. The SY88149HAL satisfies the strict timing restrictions of the GPON standards by providing ultra-fast loss-of-signal (LOS) or signal-detect (SD) output. Auto reset and manual reset options are provided to control LOS/SD output timing. The device can be connected to burst-mode capable transimpedance amplifiers (TIAs) using AC or DC coupling.

The SY88149HAL generates a high-gain LVTTL LOS or SD output. A programmable LOS/SD level set pin (LOS/SD_{LVL}) sets the sensitivity of the input amplitude detection. For increased flexibility, this device also includes an option to select between LOS or SD output by using the LOS/SD SEL pin. The LOS/SD output can be fed back to the JAM input to maintain data output stability under an invalid input signal conditions. Typically, 3dB LOS/SD hysteresis is provided to prevent chattering.

The SY88149HAL operates from a single +3.3V power supply, over temperatures ranging from -40° C to $+85^{\circ}$ C. With its wide bandwidth and high gain, signals up to 1.25Gbps and as small as 5mVpp can be amplified to LVPECL levels.

All support documentation can be found on Micrel's web site at: <u>www.micrel.com</u>.

Features

- <5ns SD Assert (LOS Deassert) time
- Option to AUTO RESET or manual RESET LOS/SD output
- Selectable LOS/SD output option
- High-sensitivity LOS/SD signal detect
- Low-noise LVPECL data outputs
- Squelching function to maintain output stability
- Programmable LOS/SD level set (LOS/SD_{LVL})
- 5mVpp input sensitivity
- 1.25Gbps operation
- Single 3.3V power supply
- Available in a 16-pin ($3mm \times 3mm$) QFN[®] package

Applications

- GE-PON/GPON
- Gigabit Ethernet
- Fibre Channel
- OC-3/12/24 SONET/SDH
- High-gain line driver and line receiver
- Low-gain TIA interface

Markets

- FTTH PON
- Datacom/Telecom
- Optical transceiver

Micrel Inc. • 2180 Fortune Drive • San Jose, CA 95131 • USA • tel +1 (408) 944-0800 • fax + 1 (408) 474-1000 • http://www.micrel.com

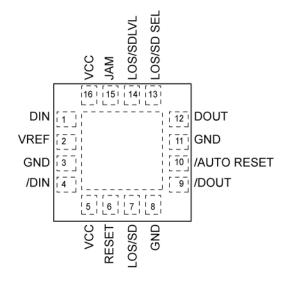
Ordering Information

Part Number Package Type		Operating Range	Package Marking
SY88149HALMG	Lead-Free QFN-16	Industrial	149A with Pb-Free Bar-Line Indicator
SY88149HALMG TR ⁽¹⁾	Lead-Free QFN-16	Industrial	149A with Pb-Free Bar-Line Indicator

Notes:

1. Tape and Reel.

Pin Configuration



16-Pin QFN[®] (QFN-16)

Pin Description

Pin Number	Pin Name	Pin Function
1, 4	DIN, /DIN	Differential Data Inputs. If AC-coupled, terminate each pin to V_{REF} with 50 Ω .
2	VREF	Reference Voltage Output. Typically V _{CC} – 1.3V.
3, 11, 8	GND	Device Ground. Exposed pad must be soldered (or equivalent) to the same potential as the ground pins.
10	/AUTO RESET	LVTTL Input. This pin is internally connected to a $25k\Omega$ pull-up resistor and defaults to HIGH. When this pin is LOW or tied to ground, the /AUTO RESET function is enabled and SD deasserts or LOS asserts within 120ns (typical) after the last high-to-low transition of the burst input. When this pin is left floating or tied high, the AUTO RESET function is disabled and the SD deassert or LOS assert must be forced by using the manual RESET function.
5, 16	VCC	Positive power supply. Bypass with 0.1uF 0.01uF low ESR capacitors. 0.01uF capacitors should be as close as possible to VCC pins.
6	RESET	LVTTL Input. Apply a high-level signal (>2V) to this pin to reset the SD deassert time or LOS assert within 5ns. RESET defaults to LOW if left floating. If the /AUTO RESET function is not used, this RESET function needs to be used to quickly deassert the SD or assert LOS. This pin is internally connected to a $25k\Omega$ pull-down resistor and defaults to LOW.

Pin Description (Continued)

Pin Number	Pin Name	Pin Function
7	LOS/SD	LVTTL Output. Signal detect (SD) asserts high when the data input amplitude rises above the threshold sets by SD _{LVL} . Conversely, loss-of-signal (LOS) deasserts low when the data input amplitude rises above the threshold set by LOS_{LVL} .
12, 9	DOUT, /DOUT	LVPECL Outputs. When JAM disables the device, output DOUT is forced to logic LOW and output /DOUT is forced to logic HIGH.
13	LOS/SD SEL	Allows the user to select between whether LOS or SD is outputted on the LOS/SD pin. Also controls the polarity of the JAM input. When SD is selected, JAM is active HIGH and LOS/SD (Pin 7) operates as signal detect. Conversely, when LOS is selected, JAM is active LOW and LOS/SD operates as loss-of-signal. This pin is internally connected to a $25k\Omega$ pull-up resistor and defaults to HIGH (SD output selected).
14	LOS/SDLVL	Voltage Input. Sets the LOS/SD level. A resistor from this pin to V_{CC} sets the threshold for the data input amplitude at which LOS/SD will be asserted.
15	JAM	LVTTL Input. This JAM input acts as a squelch function and switches its polarity depending on LOS/SD SEL status. When LOS is selected, this pin is active LOW. When SD is selected, this pin is Active HIGH. To create a squelch function, connect JAM to LOS/SD. When JAM disables the device, output Q is forced to logic LOW and output /Q is forced to logic HIGH. Note that this input is internally connected to a $25k\Omega$ pull-up resistor.

Absolute Maximum Ratings⁽¹⁾

Supply Voltage (V _{CC})	0V to +4.0V
Input Voltage (DIN, /DIN)	0 to V _{CC}
Output Current (I _{OUT})	
Continuous	±50mA
Surge	±100mA
EN Voltage	0 to V _{CC}
V _{REF} Current	800µA to +500µA
SD _{LVL} Voltage	V_{REF} to V_{CC}
Lead Temperature (soldering, 20s)	
Storage Temperature (T _s)	–65°C to +150°C

Operating Ratings⁽²⁾

Supply Voltage (V _{CC})	+3.0V to +3.6V
Ambient Temperature (T _A)	–40°C to +85°C
Junction Temperature (T _J)	–40°C to +125°C
Junction Thermal Resistance ⁽³⁾	
$QFN^{\mathbb{R}}_{I}(\theta_{JA})$ Still-Air	60°C/W
$QFN^{ extsf{@}}\left(\Psi_{JB} ight)$ Junction-to-Board	38°C/W

DC Electrical Characteristics

 V_{CC} = 3.0 to 3.6V; T_A = -40°C to +85°C, typical values at V_{CC} = 3.3V, T_A = 25°C.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
I _{CC}	Power Supply Current	No output load		58	80	mA
LOS/SD _{LVL}	LOS/SD _{LVL} Voltage		V _{REF}		V _{CC}	V
V _{OH}	LVPECL Output HIGH Voltage	50 to $V_{CC}-2V$	V _{CC} - 1.085	$V_{CC} - 0.955$	$V_{CC} - 0.880$	V
Vol	LVPECL Output LOW Voltage	50 to $V_{CC}-2V$	V _{CC} - 1.830	V _{CC} - 1.705	V _{CC} – 1.555	V
IOFFSET	Input Offset Voltage				1	mV
VIHCMR	Common Mode Range	Note 4	GND + 1.4		V _{CC}	V
V_{REF}	Reference Voltage		V _{CC} -1.48	V _{CC} – 1.32	V _{CC} - 1.16	V
I _{DIN}	Input Sink Current (DIN & /DIN)	No Input Load			6	uA

LVTTL DC Electrical Characteristics

 V_{CC} = 3.0 to 3.6V; T_A = -40°C to +85°C, typical values at V_{CC} = 3.3V, T_A = 25°C.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
VIH	LVTTL Input HIGH Voltage		2.0			V
V _{IL}	LVTTL Input LOW Voltage				0.8	V
I _{IH_JAM}	JAM Input HIGH Current	$V_{IN} = V_{CC}$ $V_{IN} = 2.7V$			20 20	μA
I _{IL_JAM}	JAM Input LOW Current	V _{IN} = 0.5V	-0.3			mA
I _{IH_AR}	/AUTORESET Input HIGH Current	$V_{IN} = V_{CC}$ $V_{IN} = 2.7V$			100 20	μA
$I_{IL_{AR}}$	/AUTORESET Input LOW Current	V _{IN} = 0.5V	-0.3			mA

Notes:

1. Permanent device damage may occur if absolute maximum ratings are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2. The data sheet limits are not guaranteed if the device is operated beyond the operating ratings.

3. Thermal performance assumes the use of a 4-layer PCB. Exposed pad must be soldered to the device's most negative potential on the PCB.

4. VIHCMR is defined as common mode range of the VIH level on DIN and /DIN. It is the most positive level of the differential signal.

LVTTL DC Electrical Characteristics (Continued)

 V_{CC} = 3.0 to 3.6V; T_A = -40°C to +85°C, typical values at V_{CC} = 3.3V, T_A = 25°C.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
I _{IH_RESET}		$V_{IN} = V_{CC}$			300	
	RESET Input HIGH Current	V _{IN} = 2.7V			250	μA
I _{IL_RESET}	RESET Input LOW Current	V _{IN} = 0.5V	0			mA
V _{OH}	SD/LOS Output HIGH Level	I _{OH} = -100uA	2.1	2.7		V
V _{OL}	SD/LOS Output LOW Level	I _{OL} = 100uA		0.35	0.5	V

AC Electrical Characteristics

 V_{CC} = 3.0V to 3.6V; R_{LOAD} = 50 Ω to $V_{CC}-$ 2V; T_A = –40°C to +85°C.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
t _r , t _f	Output Rise/Fall Time (20% to 80%)	Note 5			260	ps
t _{JAM}	JAM Enable/Disable Time				2	ns
tAUTORESET	SD Deassert or LOS Assert with Auto Reset Enabled.		100	120	150	ns
t _{RESET}	RESET time constant	Note 6			5	ns
t _{ON}	SD Assert Time/LOS Deassert time				5	ns
+	Deterministic	Note 7		15		ps _{PP}
t _{JITTER}	Random	Note 8		5		ps _{RMS}
V _{ID}	Differential Input Voltage Swing	Figure 1	5		1800	mV_{PP}
V _{OD}	Differential Output Voltage Swing	$V_{ID} \ge 18 m V_{PP}$		1500		mV_{PP}
SD _{AL} /LOS _{DL}	Low SD Assert/LOS De- Assert Level	$R_{LOS/SDLVL}$ = 10k Ω , Note 9, 10		4		mV_{PP}
SD _{DL} //LOS _{AL}	Low SD Deassert /LOS Assert Level	$R_{LOS/SDLVL} = 10k\Omega$, Note 10		3		mV_{PP}
HYS∟	Low SD/LOS Hysteresis	$R_{LOS/SDLVL} = 10k\Omega$, Note 11		2.5		dB
SD _{AM} /LOS _{DM}	Medium SD Assert/LOS Deassert Level	$R_{LOS/SDLVL} = 5k\Omega$, Note 10		4.76		mV _{PP}
SD _{DM} /LOS _{AM}	Medium SD Deassert /LOS Assert Level	$R_{LOS/SDLVL} = 5k\Omega$, Note 10		3.6		mV_{PP}
HYS _M	Medium SD/LOS Hysteresis	$R_{LOS/SDLVL} = 5k\Omega$, Note 11	2	3	4	dB
SD _{AH} /LOS _{DH}	High SD Assert/LOS De- Assert Level	$R_{LOS/SDLVL} = 50\Omega$, Note 10		18		mV_{PP}
SD _{DH} /LOS _{AH}	High SD Deassert/ LOS Assert Level	$R_{LOS/SDLVL} = 50\Omega$, Note 10		12.5		mV_{PP}
HYS _H	High SD/LOS Hysteresis	$R_{LOS/SDLVL}$ = 50 Ω , Note 11	2	3	4	dB
B-3dB	3dB Bandwidth			750		MHz
A _{V(Diff)}	Differential Voltage Gain			48		dB
S ₂₁	Single-Ended Small-Signal Gain			42		dB

Notes:

5. Amplifier in limiting mode. Input is a 200MHz square wave.

6. The time between applying RESET and outputs being disabled.

7. Deterministic jitter measured using 1.25Gbps K28.7 pattern, V_{ID} = 10m V_{PP} .

8. Random jitter measured using 1.25Gbps K28.7 pattern, V_{ID} = 10m V_{PP} .

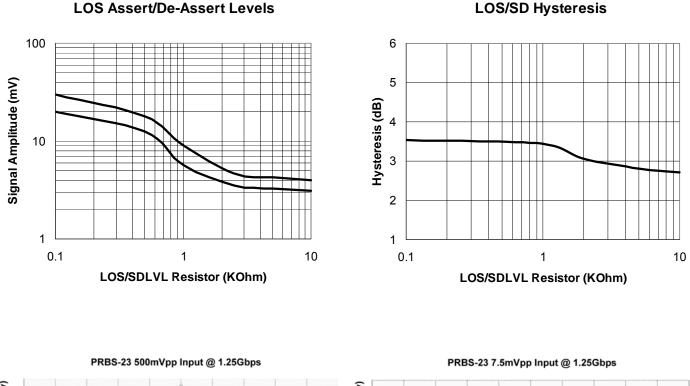
9. SD is the opposite polarity of LOS. Therefore, an SD Assert parameter is equivalent to a LOS deassert parameter and vice versa.

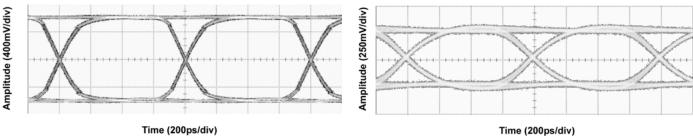
10. See "Typical Operating Characteristics" for a graph showing how to choose a particular R_{LOS/SDLVL} for a particular assert and its associated deassert amplitude.

11. This specification defines electrical hysteresis as 20log(SD assert/SD deassert). The ratio between optical hysteresis and electrical hysteresis is found to vary between 1.5 and 2 depending upon the level of received optical power and ROSA characteristics. Based upon that ratio, the optical hysteresis corresponding to the electrical hysteresis range 3dB – 6dB, shown in the AC Characteristics table, will be 1.5dB-4dB optical hysteresis.

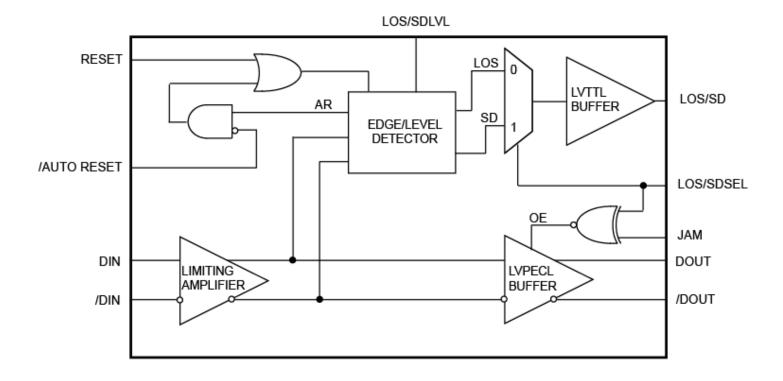
Typical Operating Characteristics

 V_{CC} = 3.3V, T_A = 25°C, R_L = 50 Ω to V_{CC} – 2V, unless otherwise stated.





Functional Block Diagram



Detailed Description

The SY88149HAL is a high-sensitivity limiting post amplifier which operates on a +3.3V power supply over the industrial temperature range. Signals with data rates up to 1.25Gbps and as small as 5mVpp can be amplified. Depending on the LOS/SD SEL option, the SY88149HAL can generate an SD or LOS output, and allow feedback to the JAM input for output stability. LOS/SD_{LVL} sets the sensitivity of the input amplitude detection.

To satisfy the stringent timing requirements of the GPON specifications, the signal detect circuit offers 5ns SD assert (LOS deassert) time and the option to deassert SD (assert LOS) using the /AUTO RESET or manual RESET function. When /AUTO RESET is enabled, SD deasserts/LOS asserts automatically within 120ns after the last high-to-low transition of the input burst. When the /AUTORESET function is disabled, the SD deassert/LOS assert time can be reset by using the provided RESET pin.

Input Buffer

Figure 2 shows a simplified schematic of the input stage. The high sensitivity of the input amplifier allows signals as small as 5mVpp to be detected and amplified. The input buffer can allow input signals as large as $1800 \text{mV}_{\text{PP}}$. Input signals are linearly amplified with a typically 48dB differential voltage gain until the outputs reach $1500 \text{mV}_{\text{PP}}$ (typical). Applications requiring the SY88149HAL to operate with high-gain should have the upstream TIA placed as close as possible to the SY88149HAL's input pins. This ensures the best performance of the device.

Output Buffer

The SY88149HAL's LVPECL output buffer is designed to drive 50 Ω lines. The output buffer requires appropriate termination for proper operation. An external 50 Ω resistor to V_{CC} – 2V for each output pin provides this. Figure 3 shows a simplified schematic of the output stage.

Loss of Signal/Signal Detect

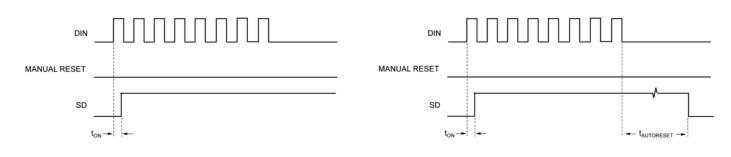
The SY88149HAL generates a chatter-free Signal-Detect (SD) or LOS LVTTL output, as shown in Figure 4. A highly-sensitive signal detect circuit is used to determine that the input amplitude is too small to be considered a valid input. LOS asserts high if the input amplitude falls below the threshold sets by LOS/SDLVL and deasserts low otherwise. SD asserts high if the input amplitude rises above threshold set by LOS/SDLVL and deasserts low otherwise. LOS/SD can be fed back to the JAM input to maintain output stability under the absence of an invalid signal condition. Typically, a 3dB hysteresis is provided to prevent chattering.

LOS/SD Level Set

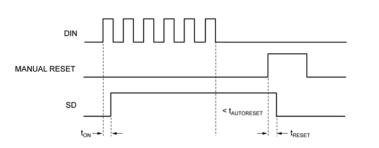
A programmable LOS/SD level pin (LOS/SD_{LVL}) sets the threshold of the input amplitude detection. Connecting an external resistor between V_{CC} and LOS/SD_{LVL} sets the voltage at LOS/SD_{LVL}. This voltage ranges from V_{CC} to V_{REF}. The external resistor creates a voltage divider between V_{CC} and V_{REF}, as shown in Figure 5. Set the LOS/SD_{LVL} voltage closer to V_{REF} or more sensitive LOS/SD detection or closer to V_{CC} for higher inputs.

No Manual RESET and /AUTORESET Tied LOW

Timing Diagrams



No Manual RESET and /AUTORESET Tied HIGH



Manual RESET and /AUTORESET Tied HIGH or LOW

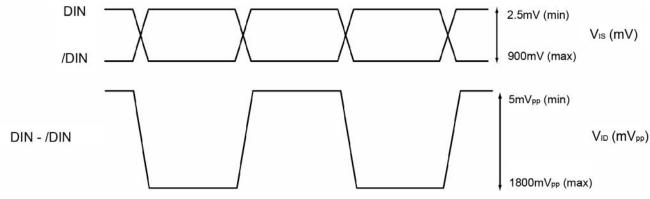


Figure 1. VIS and VID Definition

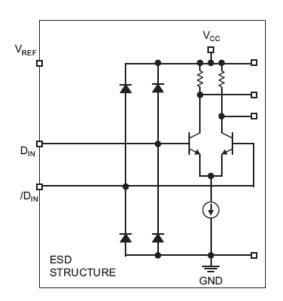


Figure 2. Input Structure

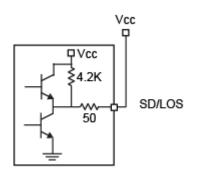


Figure 4. SD Output Structure

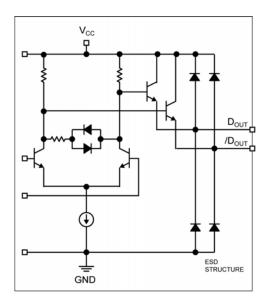


Figure 3. Output Structure

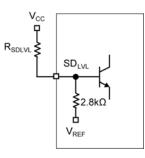
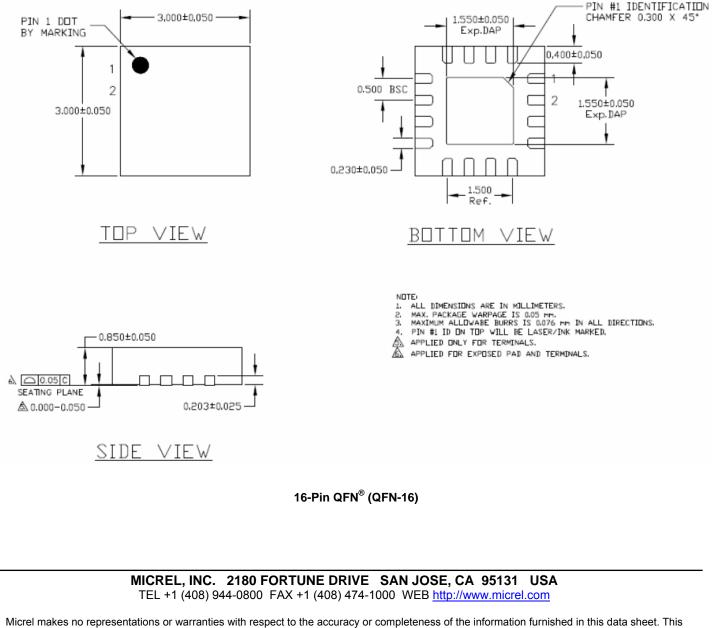


Figure 5. LOS/SD_{LVL} Setting Circuit

Package Information



information is not intended as a warranty and Micrel does not assume responsibility for its use. Micrel reserves the right to change circuitry, specifications and descriptions at any time without notice. No license, whether express, implied, arising by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Micrel's terms and conditions of sale for such products, Micrel assumes no liability whatsoever, and Micrel disclaims any express or implied warranty relating to the sale and/or use of Micrel products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright or other intellectual property right.

Micrel Products are not designed or authorized for use as components in life support appliances, devices or systems where malfunction of a product can reasonably be expected to result in personal injury. Life support devices or systems are devices or systems that (a) are intended for surgical implant into the body or (b) support or sustain life, and whose failure to perform can be reasonably expected to result in a significant injury to the user. A Purchaser's use or sale of Micrel Products for use in life support appliances, devices or systems is a Purchaser's own risk and Purchaser agrees to fully indemnify Micrel for any damages resulting from such use or sale.

© 2011 Micrel, Incorporated.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Limiting Amplifiers category:

Click to view products by Microchip manufacturer:

Other Similar products are found below :

HMC750LP4E HMC865LC3 HMC866LC3 SY88403BLEY MAX3747BEUB+T MAX3272AETP+T MAX3711ETG+ MAX3645EEE+ MAX3645EEE+T MAX3861ETG+ SY88993AVKG MAX3748HETE+T SY88083LMG SY88773VMG SY88053CLMG SY88073LMG SY88149HLMG SY88923VKG SY88903VKG-TR SY88903ALKG-TR SY88813VKG SY88303BLMG SY88149NDLMG-TR SY88303BLEY SY88349NDLMG SY88803VKG SY88933VKG SY88053CLMG-TR ONET1191PRGTT ONET4201PARGTR ONET4251PARGTR ONET8501PBRGTR ONET8501PBRGTT ONET1191PRGTR MAX3945ETE+ MAX3748HETE#G16 MAX3268CUB+ SY88943VKG SY88149HALMG MAX3945ETE+T ONET4201PARGTT